






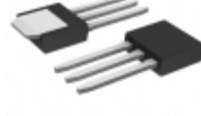


	<h2 style="color: red;">NTD110N02R</h2>
	<p>Hersteller-Teilenummer: NTD110N02R</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 24V 12.5A DPAK</p> <p>Datenblätter:  NTD110N02R.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 1487 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen	
Teilenummer	NTD110N02R
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 24V 12.5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1487 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 110W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	24V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.5A (Ta), 110A (Tc)
Rds On (Max) @ Id, Vgs	4.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	28nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	3440pF @ 20V
Verpackung	Tube



















































NTD110N02R ist neu im Original, Suche NTD110N02R Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD110N02R AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD110N02R: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD110N02RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A DPAK</p>	 <p>NTD014L FAIRCHILD FAIRCHILD SOT-223</p>	 <p>NTD110N02 ON NTD110N02 ON</p>	 <p>NTD110N02RST4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 100A DPAK</p>
 <p>NTD110N02R-1 ON NTD110N02R-1 ON</p>	 <p>NTD110N02R-001G AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A IPAK</p>	 <p>NTD110N02RG AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A DPAK</p>	 <p>NTD110N02R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A IPAK</p>

heiße Teile

Mehr

 NTD110N02	 NTD110N02R-001	 NTD110N02R-001G	 NTD110N02RG	 NTD110N02RT4G
 NTD12N10-001	 NTD12N10-1G	 NTD12N10G	 NTD12N10T4	 NTD12N10T4G
 NTD14N03	 NTD14N03G	 NTD14N03R	 NTD14N03R-001	 NTD14N03R-1
 NTD14N03R-1G	 NTD14N03RG	 NTD14N03RT4	 NTD14N03RT4G	 NTD14N03RTCG
 NTD14N03T4G	 NTD15N06	 NTD15N06L	 NTD15N06LG	 NTD15N06LT4
 NTD15N06LT4G	 NTD15N06T4	 NTD15N06T4G	 NTD15N06VLT4	 NTD15N07
 NTD15N10	 NTD18N06-001	 NTD18N06-1G	 NTD18N06G	 NTD18N06L
 NTD18N06L-1G	 NTD18N06LG	 NTD18N06LT4G	 NTD18N06T4G	 NTD20N03
 NTD20N03G	 NTD20N03HL	 NTD20N03L27	 NTD20N03L27G	 NTD20N03L27T
 NTD20N03L27T4	 NTD20N03L27T4G	 NTD20N03RT4G	 NTD20N06	 NTD20N06-001

Contact us: Info@Y-IC.com

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